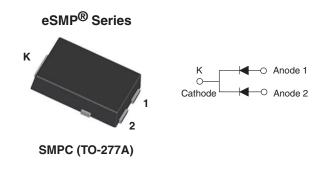
www.vishay.com

# Hyperfast Rectifier, 2 x 4 A FRED Pt<sup>®</sup>



click logo to get started

### **DESIGN SUPPORT TOOLS**



PRIMARY CHARACTERISTICS					
I <sub>F(AV)</sub>	2 x 4 A				
V <sub>R</sub>	100 V				
V <sub>F</sub> at I <sub>F</sub>	0.72 V				
t <sub>rr</sub> (typ.)	25 ns				
T <sub>J</sub> max.	175 °C				
Package	SMPC (TO-277A)				
Circuit configuration	Common cathode				

### **FEATURES**

- Hyperfast recovery time, reduced Q<sub>rr</sub>, and soft recovery
- 175 °C maximum operating junction temperature
- Specified for output and snubber operation
- Low forward voltage drop
- Low leakage current
- Meets MSL level 1, per J-STD-020, LF maximum peak of 260 °C
- Meets JESD 201 class 2 whisker test
- Material categorization: for definitions of compliance please see www.vishay.com/doc?99912

### **DESCRIPTION / APPLICATIONS**

State of the art hyperfast recovery rectifiers specifically designed with optimized performance of forward voltage drop and hyperfast recovery time.

The planar structure and the platinum doped life time control guarantee the best overall performance, ruggedness, and reliability characteristics.

These devices are intended for use in snubber, boost, as high frequency rectifiers and freewheeling diodes.

The extremely optimized stored charge and low recovery current minimize the switching losses and reduce power dissipation in the switching element.

ABSOLUTE MAXIMUM RATINGS							
PARAMETER		SYMBOL	TEST CONDITIONS	VALUES	UNITS		
Peak repetitive reverse voltage		V <sub>RRM</sub>		100	V		
Average rectified forward current	per device	1	T <sub>Sp</sub> = 160 °C	8	A		
Average rectilied forward current	per diode	I <sub>F(AV)</sub>	1 <sub>Sp</sub> = 100 C	4			
Non repetitive peak ourse ourrept	per device	I	T <sub>1</sub> = 25 °C	130			
Non-repetitive peak surge current per diode		IFSM	1J=25 C	70			
Operating junction and storage temperatures		TJ, T <sub>Stg</sub>		-55 to +175	°C		

<b>ELECTRICAL SPECIFICATIONS</b> ( $T_J = 25 \text{ °C}$ unless otherwise specified)						
PARAMETER	SYMBOL	TEST CONDITIONS	MIN.	TYP.	MAX.	UNITS
Breakdown voltage, blocking voltage	V <sub>BR</sub> , V <sub>R</sub>	I <sub>R</sub> = 100 μA	100	-	-	
Forward voltage, per diode V <sub>F</sub>	M	$I_F = 4 A$	-	0.89	0.95	V
	۷F	I <sub>F</sub> = 4 A, T <sub>J</sub> = 150 °C	-	0.72	0.78	
		$V_{R} = V_{R}$ rated	-	-	2	
Reverse leakage current, per diode	IR	$T_J = 150 \text{ °C}, V_R = V_R \text{ rated}$	-	4	80	μA
Junction capacitance	CT	V <sub>R</sub> = 100 V	-	18	-	pF

Revision: 05-Feb-2019 Document Number: 95704 1 For technical questions within your region: DiodesAmericas@vishay.com, DiodesAsia@vishay.com, DiodesEurope@vishay.com THIS DOCUMENT IS SUBJECT TO CHANGE WITHOUT NOTICE. THE PRODUCTS DESCRIBED HEREIN AND THIS DOCUMENT ARE SUBJECT TO SPECIFIC DISCLAIMERS, SET FORTH AT www.vishav.com/doc?91000



e?



<b>DYNAMIC RECOVERY CHARACTERISTICS</b> ( $T_J = 25$ °C unless otherwise specified)								
PARAMETER	SYMBOL	TEST CO	MIN.	TYP.	MAX.	UNITS		
		$I_F = 1 \text{ A}, \ dI_F/dt = 50 \text{ A}$	Α/μs, V <sub>R</sub> = 30 V	-	25	-		
Povereo recover timo	Reverse recovery time t <sub>rr</sub>	$I_F = 0.5 \text{ A}, I_R = 1 \text{ A}, I_{rr} = 0.25 \text{ A}$		-	-	25		
Reverse recovery lime		T <sub>J</sub> = 25 °C		-	18	-	ns	
		T <sub>J</sub> = 125 °C		-	27	-		
Deals receivers ourrent		T <sub>J</sub> = 25 °C	$I_F = 4 A$	-	2	-	А	
Peak recovery current I <sub>RRM</sub>	T <sub>J</sub> = 125 °C	dl <sub>F</sub> /dt = 200 A/µs V <sub>R</sub> = 160 V	-	3.6	-	~		
Reverse recovery charge Q <sub>rr</sub>	0	T <sub>J</sub> = 25 °C		-	18	-		
	T <sub>J</sub> = 125 °C		-	50	-	nC		

THERMAL - MECHANICAL SPECIFICATIONS						
PARAMETER	SYMBOL	TEST CONDITIONS	MIN.	TYP.	MAX.	UNITS
Maximum junction and storage temperature range	T <sub>J</sub> , T <sub>Stg</sub>		-55	-	175	°C
Thermal resistance, junction to solder pad, per leg	R <sub>thJ-Sp</sub>		-	2.5	3.5	°C/W
Thermal resistance, junction to ambient, per leg	R <sub>thJA</sub>		-	80	-	°C/W
Approximate weight				0.1		g
Approximate weight				0.0035		oz.
Marking device		Case style SMPC (TO-277A)		QC	CH1	

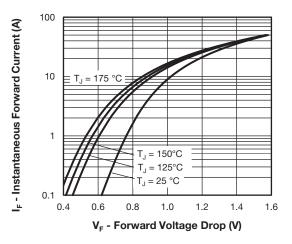


Fig. 1 - Typical Forward Voltage Drop Characteristics

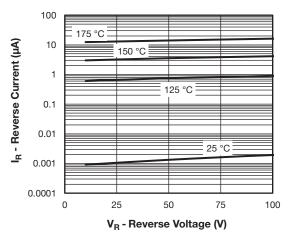


Fig. 2 - Typical Values of Reverse Current vs. Reverse Voltage





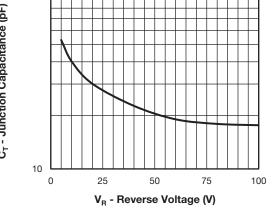


Fig. 3 - Typical Junction Capacitance vs. Reverse Voltage

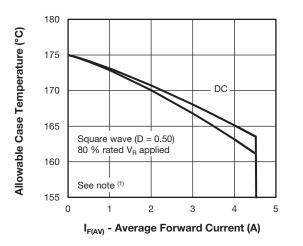


Fig. 4 - Maximum Allowable Case Temperature vs. Average Forward Current

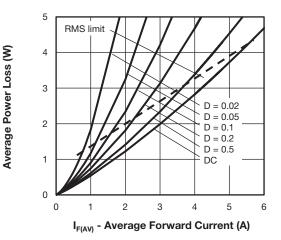
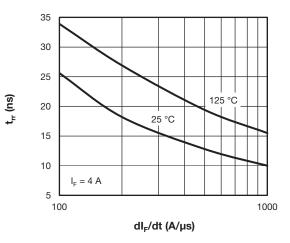


Fig. 5 - Forward Power Loss Characteristics





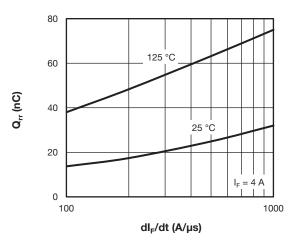


Fig. 7 - Typical Stored Charge vs. dl<sub>F</sub>/dt

#### Note

<sup>(1)</sup> Formula used:  $T_C = T_J - (Pd + Pd_{REV}) \times R_{thJC}$ ;

 $\begin{array}{l} \mathsf{Pd} = \mathsf{forward} \ \mathsf{power} \ \mathsf{loss} = \mathsf{I}_{\mathsf{F}(\mathsf{AV})} \ \mathsf{x} \ \mathsf{V}_{\mathsf{FM}} \ \mathsf{at} \ (\mathsf{I}_{\mathsf{F}(\mathsf{AV})}/\mathsf{D}) \ (\mathsf{see} \ \mathsf{fig. 5}); \\ \mathsf{Pd}_{\mathsf{REV}} = \mathsf{inverse} \ \mathsf{power} \ \mathsf{loss} = \mathsf{V}_{\mathsf{R1}} \ \mathsf{x} \ \mathsf{I}_{\mathsf{R}} \ (\mathsf{1} - \mathsf{D}); \ \mathsf{I}_{\mathsf{R}} \ \mathsf{at} \ \mathsf{V}_{\mathsf{R1}} = \mathsf{rated} \ \mathsf{V}_{\mathsf{R}} \end{array}$ 

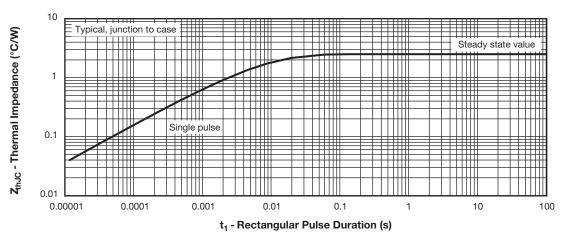
Revision: 05-Feb-2019

3

Document Number: 95704

For technical questions within your region: DiodesAmericas@vishay.com, DiodesAsia@vishay.com, DiodesEurope@vishay.com THIS DOCUMENT IS SUBJECT TO CHANGE WITHOUT NOTICE. THE PRODUCTS DESCRIBED HEREIN AND THIS DOCUMENT ARE SUBJECT TO SPECIFIC DISCLAIMERS, SET FORTH AT www.vishay.com/doc?91000





SHA

www.vishay.com

Fig. 8 - Typical Transient Thermal Impedance, Junction to Case

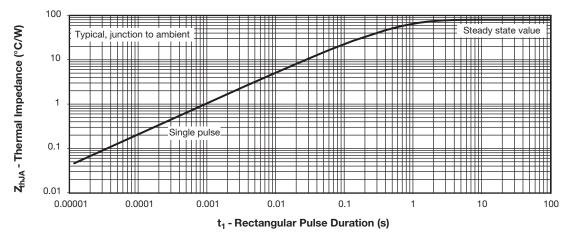
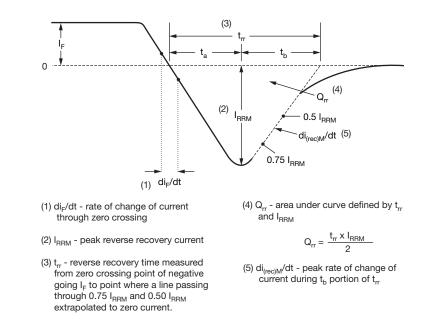
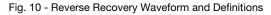


Fig. 9 - Typical Transient Thermal Impedance, Junction to Ambient





Revision: 05-Feb-2019	4	Document Number: 95704
For technical questions within your region	n: <u>DiodesAmericas@vishay.com</u> , <u>DiodesAsia@visha</u>	<u>y.com, DiodesEurope@vishay.com</u>
	GE WITHOUT NOTICE. THE PRODUCTS DESCRIB CIFIC DISCLAIMERS, SET FORTH AT <u>www.vishay.</u>	

www.vishay.com

### **ORDERING INFORMATION TABLE**

Device code	VS-	8	С	s	н	01	-M3
	1	2	3	4	5	6	7
	1	- Visl	nay Sen	niconduo	ctors pro	oduct	
	2	- Cur	rent rati	ng (8 = 8	8 A)		
	3	- Circ	cuit conf	iguratior	า:		
		C =	commo	n catho	de		
	4	- S=	SMPC	package	)		
	5	- Pro	cess typ	be,			
	_	H =	hyper fa	ast reco	very		
	6	- Vol	tage coo	de (01 =	100 V)		
	7	M3	= halog	gen-free	, RoHS-	complia	ant, and

ORDERING INFORMATION (Example)								
PREFERRED P/N	QUANTITY PER REEL	MINIMUM ORDER QUANTITY	PACKAGING DESCRIPTION					
VS-8CSH01-M3/86A	1500	1500	7" diameter plastic tape and reel					
VS-8CSH01-M3/87A	6500	6500	13" diameter plastic tape and reel					

LINKS TO RELATED DOCUMENTS					
Dimensions	www.vishay.com/doc?95570				
Part marking information	www.vishay.com/doc?95565				
Packaging information	www.vishay.com/doc?88869				
SPICE model	www.vishay.com/doc?96095				

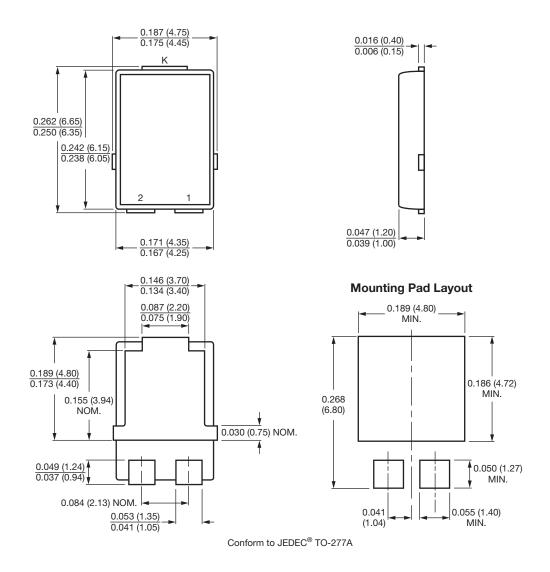
# **Outline Dimensions**





TO-277A (SMPC)

### **DIMENSIONS** in inches (millimeters)





Vishay

# Disclaimer

ALL PRODUCT, PRODUCT SPECIFICATIONS AND DATA ARE SUBJECT TO CHANGE WITHOUT NOTICE TO IMPROVE RELIABILITY, FUNCTION OR DESIGN OR OTHERWISE.

Vishay Intertechnology, Inc., its affiliates, agents, and employees, and all persons acting on its or their behalf (collectively, "Vishay"), disclaim any and all liability for any errors, inaccuracies or incompleteness contained in any datasheet or in any other disclosure relating to any product.

Vishay makes no warranty, representation or guarantee regarding the suitability of the products for any particular purpose or the continuing production of any product. To the maximum extent permitted by applicable law, Vishay disclaims (i) any and all liability arising out of the application or use of any product, (ii) any and all liability, including without limitation special, consequential or incidental damages, and (iii) any and all implied warranties, including warranties of fitness for particular purpose, non-infringement and merchantability.

Statements regarding the suitability of products for certain types of applications are based on Vishay's knowledge of typical requirements that are often placed on Vishay products in generic applications. Such statements are not binding statements about the suitability of products for a particular application. It is the customer's responsibility to validate that a particular product with the properties described in the product specification is suitable for use in a particular application. Parameters provided in datasheets and / or specifications may vary in different applications and performance may vary over time. All operating parameters, including typical parameters, must be validated for each customer application by the customer's technical experts. Product specifications do not expand or otherwise modify Vishay's terms and conditions of purchase, including but not limited to the warranty expressed therein.

Except as expressly indicated in writing, Vishay products are not designed for use in medical, life-saving, or life-sustaining applications or for any other application in which the failure of the Vishay product could result in personal injury or death. Customers using or selling Vishay products not expressly indicated for use in such applications do so at their own risk. Please contact authorized Vishay personnel to obtain written terms and conditions regarding products designed for such applications.

No license, express or implied, by estoppel or otherwise, to any intellectual property rights is granted by this document or by any conduct of Vishay. Product names and markings noted herein may be trademarks of their respective owners.